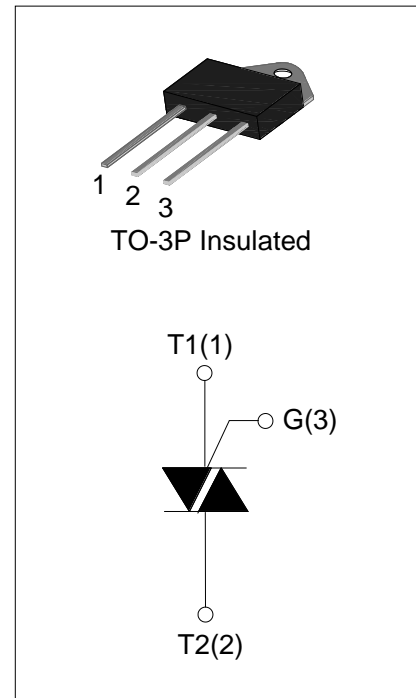


**BTA26 25A TRIACs**
**DESCRIPTION:**

BTA26 provide high dv/dt rate with strong resistance to electromagnetic interference. With high commutation performances, 3 quadrants products especially recommended for use on inductive load.


**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	25	A
$V_{DRM}/V_{RRM}$	600 and 800 and 1200	V

**ABSOLUTE MAXIMUM RATINGS**

Parameter		Symbol	Value	Unit
Storage junction temperature range		$T_{stg}$	-40-150	°C
Operating junction temperature range		$T_j$	-40-125	°C
Repetitive peak off-state voltage ( $T_j=25^\circ\text{C}$ )		$V_{DRM}$	600/800/1200	V
Repetitive peak reverse voltage ( $T_j=25^\circ\text{C}$ )		$V_{RRM}$	600/800/1200	V
Non repetitive surge peak Off-state voltage		$V_{DSM}$	$V_{DRM} + 100$	V
Non repetitive peak reverse voltage		$V_{RSM}$	$V_{RRM} + 100$	V
RMS on-state current	TO-3P(Ins) ( $T_C=100^\circ\text{C}$ )	$I_{T(RMS)}$	25	A
Non repetitive surge peak on-state current (full cycle, $F=50\text{Hz}$ )		$I_{TSM}$	250	A
$I^2t$ value for fusing ( $t_p=10\text{ms}$ )		$I^2t$	340	$\text{A}^2\text{s}$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ )		$di/dt$	50	$\text{A}/\mu\text{s}$
Peak gate current		$I_{GM}$	4	A
Average gate power dissipation		$P_{G(AV)}$	1	W

Peak gate power	$P_{GM}$	10	W
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**ELECTRICAL CHARACTERISTICS** ( $T_j=25^{\circ}C$  unless otherwise specified)

$V_{DRM}/V_{RRM}$ : 600/800V

Symbol	Test Condition	Quadrant		BTA26 -600/800V		Unit
				BW	CW	
$I_{GT}$	$V_D=12V R_L=33\Omega$	I - II -III	MAX	50	35	mA
$V_{GT}$		I - II -III	MAX	1.3		V
$V_{GD}$	$V_D=V_{DRM} T_j=125^{\circ}C$ $R_L=3.3K\Omega$	I - II -III	MIN	0.2		V
$I_L$	$I_G=1.2I_{GT}$	I -III	MAX	80	70	mA
		II		100	80	
$I_H$	$I_T=100mA$		MAX	75	50	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^{\circ}C$		MIN	1000	500	V/ $\mu s$

$V_{DRM}/V_{RRM}$ : 1200V

Symbol	Test Condition	Quadrant		BTA26 -1200V		Unit
				BW	CW	
$I_{GT}$	$V_D=12V R_L=33\Omega$	I - II -III	MAX	50	35	mA
$V_{GT}$		I - II -III	MAX	1.5		V
$V_{GD}$	$V_D=V_{DRM} T_j=125^{\circ}C$ $R_L=3.3K\Omega$	I - II -III	MIN	0.2		V
$I_L$	$I_G=1.2I_{GT}$	I -III	MAX	90	70	mA
		II		100	80	
$I_H$	$I_T=100mA$		MAX	80	60	mA
dV/dt	$V_D=2/3V_{DRM}$ Gate Open $T_j=125^{\circ}C$		MIN	1500	1000	V/ $\mu s$

**STATIC CHARACTERISTICS**

Symbol	Parameter		Value(MAX)	Unit
$V_{TM}$	$I_{TM}=35A$ $t_p=380\mu s$	$T_j=25^{\circ}C$	1.5	V
$I_{DRM}$	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^{\circ}C$	5	$\mu A$
$I_{RRM}$		$T_j=125^{\circ}C$	3	mA

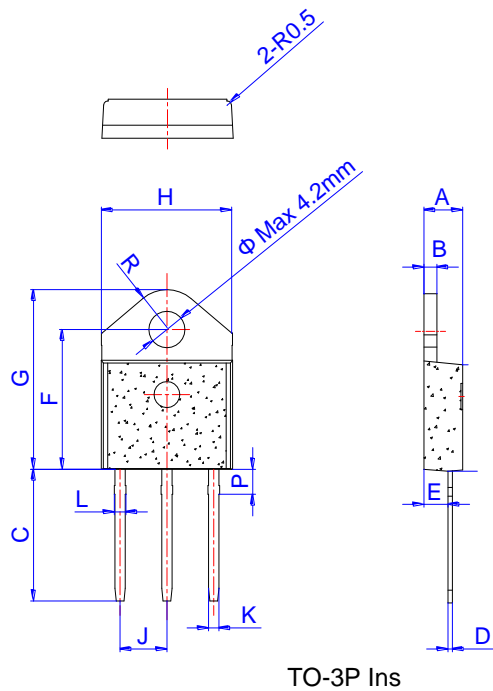
**THERMAL RESISTANCES**

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-3P(Ins)	0.8	°C/W

**ORDERING INFORMATION**

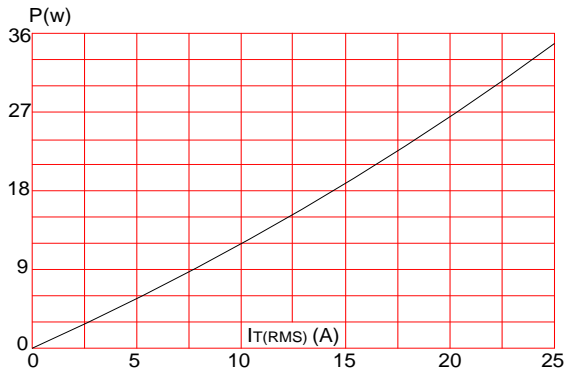
<p><b>BTA</b></p> <p>TRIAC SERIES</p>	<p><b>26</b></p> <p><math>I_{T(RMS)}:25A</math></p>	<p>-</p>	<p><b>600</b></p> <p>600: <math>V_{DRM}/V_{RRM} \geq 600V</math>              800: <math>V_{DRM}/V_{RRM} \geq 800V</math>              1200: <math>V_{DRM}/V_{RRM} \geq 1200V</math></p>	<p><b>BW</b></p> <p>BW: <math>I_{GT3} \leq 50mA</math>              CW: <math>I_{GT3} \leq 35mA</math></p>
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**PACKAGE MECHANICAL DATA**

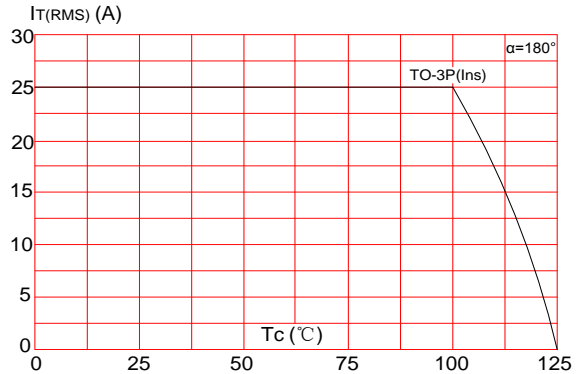


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.35		1.50	0.053		0.059
P	2.80		3.00	0.110		0.118
R		4.35			0.171	

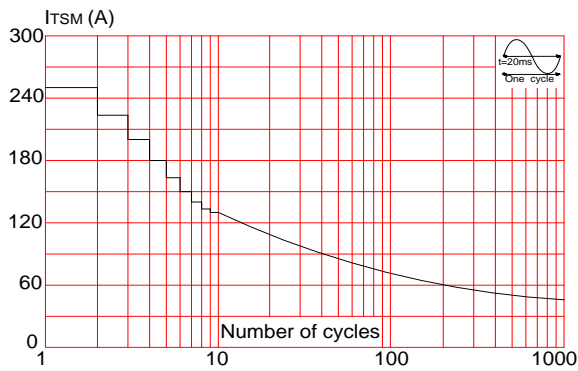
**FIG.1:** Maximum power dissipation versus RMS on-state current



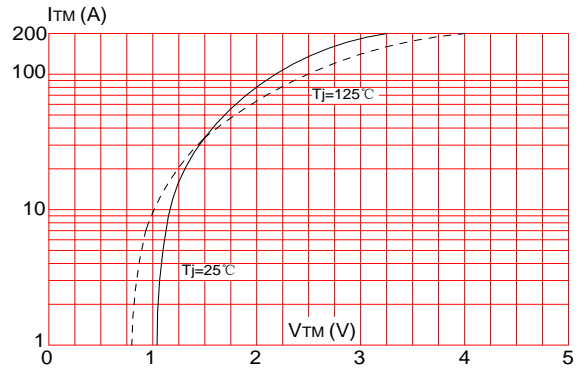
**FIG.2:** RMS on-state current versus case temperature



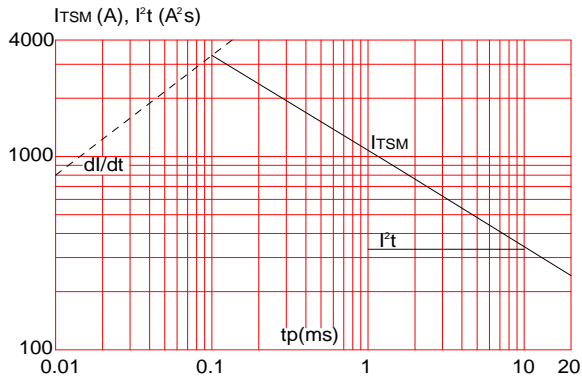
**FIG.3:** Surge peak on-state current versus number of cycles



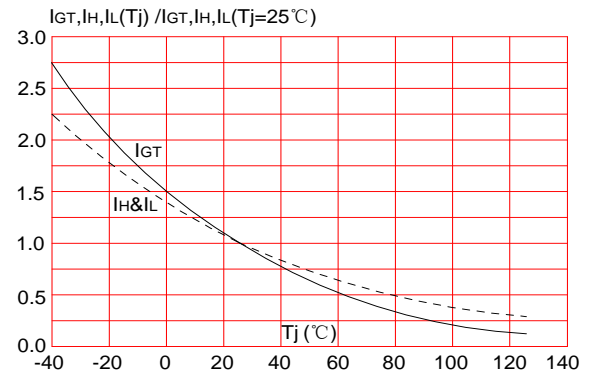
**FIG.4:** On-state characteristics (maximum values)



**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10\text{ms}$ , and corresponding value of  $I^2t$  ( $di/dt < 50\text{A}/\mu\text{s}$ )



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



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